

LT1303/LT1303-5

Micropower High Efficiency DC/DC Converters with Low-Battery Detector Adjustable and Fixed 5V

FEATURES

- 5V at 200mA from a 2V Input
- Supply Voltage As Low As 1.8V
- Up to 88% Efficiency
- 120µA Quiescent Current
- Low-Battery Detector
- Low V_{CESAT} Switch: 170mV at 1A Typ
- Uses Inexpensive Surface Mount Inductors
- 8-Lead PDIP or SO Package

APPLICATIONS

- EL Panel Drivers
- 2-Cell and 3-Cell to 5V Conversion
- Palmtop Computers
- Portable Instruments
- Bar-Code Scanners
- PDAs
- Wireless Systems

L1 1N5817 22uH 316k VIN SW 1% V_{OUT}, 5V LBI SENSE 200mA 412k LT1303-5 2 CELLS 100µF 100k LOW BATTERY SHUTDOWN SHDN GOES LOW AT LBO $V_{BAT} = 2.2V$ PGND + GND 100µF L1 = SUMDIA CD54-220 LT1303 TA02

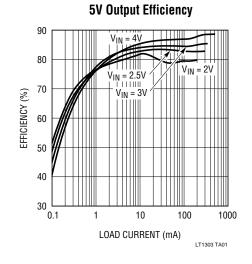


DESCRIPTION

The LT[®]1303/LT1303-5 are micropower step-up high efficiency DC/DC converters using Burst ModeTM operation. They are ideal for use in small, low-voltage battery-operated systems. The LT1303-5 accepts an input voltage between 1.8V and 5V and converts it to a regulated 5V. The LT1303 is an adjustable version that can supply an output voltage up to 25V. Quiescent current is only 120µA from the battery and the shutdown pin further reduces current to 10µA. The low-battery detector provides an open-collector output that goes low when the input voltage drops below a preset level. The on-chip NPN power switch has a low 170mV saturation voltage at a switch current of 1A. The LT1303/LT1303-5 are available in 8-lead PDIP or SO packages, easing board space requirements.

For higher output current, please see the LT1305 or LT1302.

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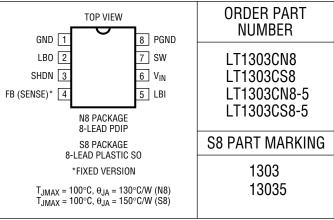


TYPICAL APPLICATION

ABSOLUTE MAXIMUM RATINGS

| V _{IN} Voltage | 10V |
|--------------------------------------|---------------|
| SW1 Voltage | 25V |
| Sense Voltage (LT1303-5) | 20V |
| FB Voltage (LT1303) | 10V |
| Shutdown Voltage | 10V |
| LBO Voltage | 10V |
| LBI Voltage | 10V |
| Maximum Power Dissipation | 500mW |
| Operating Temperature Range | 0°C to 70°C |
| Storage Temperature Range | 65°C to 150°C |
| Lead Temperature (Soldering, 10 sec) | 300°C |

PACKAGE/ORDER INFORMATION



Consult factory for Industrial and Military grade parts.

ELECTRICAL CHARACTERISTICS $T_A = 25 \degree C$, $V_{IN} = 2.0V$, unless otherwise noted.

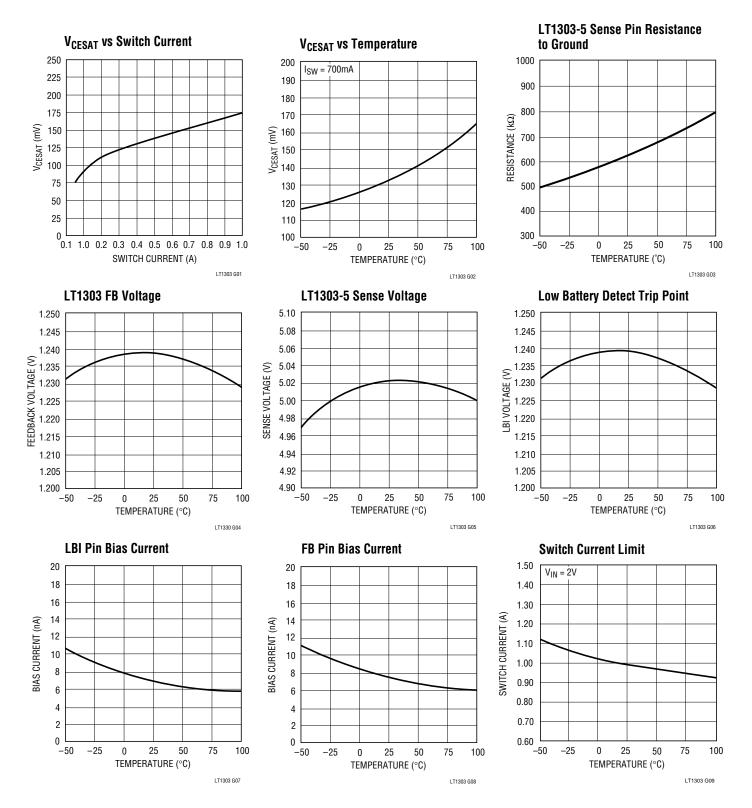
| SYMBOL | PARAMETER | CONDITIONS | | MIN | ТҮР | MAX | UNITS |
|--------------------|---------------------------|--|---|------|------|------|-------|
| IQ | Quiescent Current | V _{SHDN} = 0.5V, V _{SEL} = 5V, V _{SENSE} = 5.5V | • | | 120 | 200 | μA |
| | | $V_{SHDN} = 1.8V$ | • | | 7 | 15 | μA |
| VIN | Input Voltage Range | | | 1.8 | 1.55 | | V |
| | | | • | 2.0 | | | V |
| | Feedback Voltage | LT1303 | • | 1.22 | 1.24 | 1.26 | V |
| | Output Sense Voltage | LT1303-5 | • | 4.8 | 5.0 | 5.2 | V |
| | Comparator Hysteresis | LT1303 (Note 1) | • | | 6 | 12.5 | mV |
| | Output Hysteresis | LT1303-5 (Note 1) | | | 22 | 50 | mV |
| | Feedback Pin Bias Current | LT1303, V _{FB} = 1V | • | | 7 | 20 | nA |
| | Oscillator Frequency | Current Limit Not Asserted | | 120 | 155 | 185 | kHz |
| | Oscillator TC | | | | 0.2 | | %/°C |
| DC | Maximum Duty Cycle | | | 75 | 86 | 95 | % |
| t _{ON} | Switch On Time | Current Limit Not Asserted | | | 5.6 | | μs |
| | Output Line Regulation | 1.8V < V _{IN} < 6V | • | | 0.06 | 0.15 | %/V |
| V _{CESAT} | Switch Saturation Voltage | I _{SW} = 700mA | • | | 130 | 200 | mV |
| | Switch Leakage Current | V _{SW} = 5V, Switch Off | • | | 0.1 | 10 | μA |
| | Peak Switch Current | V _{IN} = 2V | • | 0.75 | 1.0 | 1.25 | A |
| | | $V_{IN} = 5V$ | | 0.65 | 0.9 | 1.15 | A |
| | LBI Trip Voltage | | • | 1.21 | 1.24 | 1.27 | V |
| | LBI Input Bias Current | V _{LBI} = 1V | • | | 7 | 20 | nA |
| | LBO Output Low | I _{LOAD} = 100μA | • | | 0.11 | 0.4 | V |
| | LBO Leakage Current | V _{LBI} = 1.3V, V _{LBO} = 5V | | | 0.1 | 5 | μA |
| V _{SHDNH} | Shutdown Pin High | | • | 1.8 | | | V |
| V _{SHDNL} | Shutdown Pin Low | | | | | 0.5 | V |
| I _{SHDN} | Shutdown Pin Bias Current | V _{SHDN} = 5V | • | | 8.0 | 20 | μA |
| | | $V_{SHDN} = 2V$ | | | 3.0 | | μA |
| | | V _{SHDN} = 0V | | | 0.1 | 1 | μA |

The \bullet denotes specifications which apply over the 0°C to 70°C operating temperature range.

Note 1: Hysteresis specified is DC. Output ripple may be higher if output capacitance is insufficient or capacitor ESR is excessive.

2

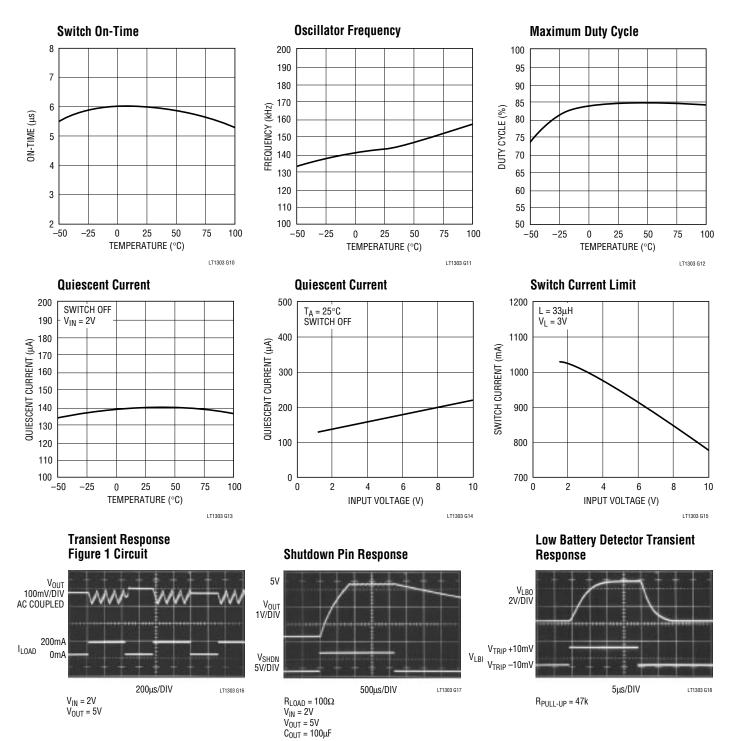
TYPICAL PERFORMANCE CHARACTERISTICS





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TYPICAL PERFORMANCE CHARACTERISTICS





PIN FUNCTIONS

GND (Pin 1): Signal Ground. Tie to PGND under the package.

LBO (Pin 2): Open-Collector Output of Low-Battery Comparator. Can sink $100\mu A$. Disabled when device is in shutdown.

SHDN (Pin 3): Shutdown. Pull high to shut down the device. Ground for normal operation.

FB/Sense (Pin 4): On 1303 (adjustable) this pin connects to the main comparator C1 input. On LT1303-5 this pin connects to the resistor string that sets output voltage at 5V.

LBI (Pin 5): Low-Battery Comparator Input. When voltage on this pin below 1.24V, LBO is low.

 V_{IN} (Pin 6): Supply Pin. Must be bypassed with a large value electrolytic to ground. Keep bypass within 0.2" of the device.

SW (Pin 7): Switch Pin. Connect inductor and diode here. Keep layout short and direct to minimize radio frequency interference.

PGND (Pin 8): Power ground. Tie to signal ground (pin1) under the package. Bypass capacitor from V_{IN} should be tied directly to PGND within 0.2" of the device.

BLOCK DIAGRAMS

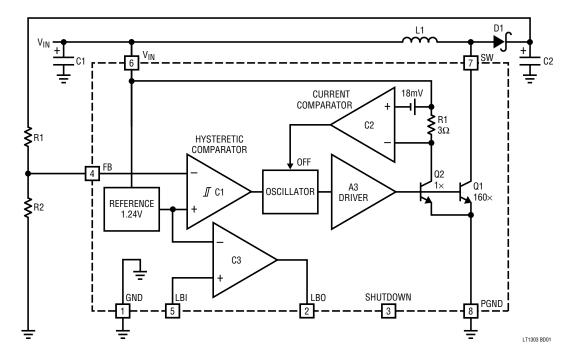
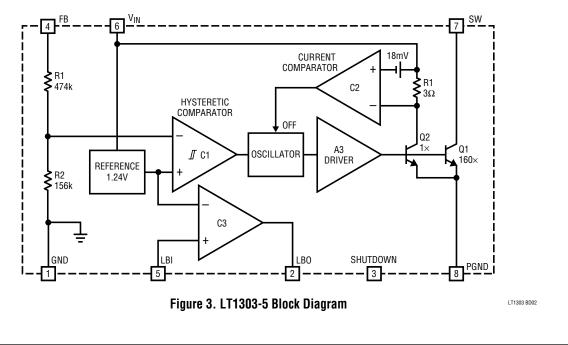


Figure 2. LT1303 Block Digram

BLOCK DIAGRAMS



OPERATION

Operation of the LT1303 is best understood by referring to the Block Diagram in Figure 2. When C1's negative input, related to the output voltage by the appropriate resistordivider ratio, is higher than the 1.24V reference voltage, C1's output is low. C2, A3 and the oscillator are turned off, drawing no current. Only the reference and C1 consume current, typically 140µA. When C1's negative input drops below 1.24V and overcomes C1's 6mV hysteresis, C1's output goes high, enabling the oscillator, current comparator C2 and driver A3. Quiescent current increases to 2mA as the device goes into active switching mode. Q1 then turns on in controlled saturation for nominally 6us or until current comparator C2 trips, whichever comes first. The switch then turns off for approximately 1.5 µs, then turns on again. The LT1303's switching causes current to alternately build up in L1 and dump into output capacitor C4 via D1, increasing the output voltage. When the output is high enough to cause C1's output to go high, switching action ceases. Capacitor C4 is left to supply current to the load until V_{OUT} decreases enough to force C1's output high, and the entire cycle repeats. Figure 4 details relevant waveforms. C1's cycling causes low-to-mid-frequency ripple voltage on the output. Ripple can be reduced by making the output capacitor large. The 100μ F unit specified results in ripple of 50mV to 100mV on the 5V output. A 220μ F capacitor will decrease ripple by approximately 50%.

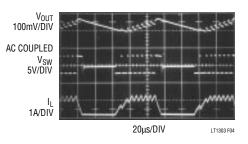


Figure 4. Burst Mode Operation in Action

If switch current reaches 1A, causing C2 to trip, switch ontime is reduced and off-time increases slightly. This allows continuous operation during bursts. C2 monitors the voltage across 3Ω resistor R1 which is directly related to the switch current. Q2's collector current is set by the emitter-area ratio to 0.6% of Q1's collector current. When R1's voltage drop exceeds 18mV, corresponding to 1A switch current, C2's output goes high, truncating the ontime portion of the oscillator cycle and increasing off-time



OPERATION

to about $2\mu s$. Response time of C2, which determines minimum on-time, is approximately 300ns.

Low Battery Detector

The low battery detector is enabled when SHDN is low and disabled when SHDN is high. The comparator has no

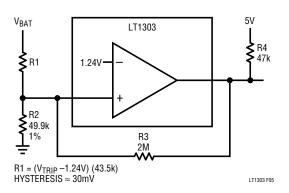


Figure 5. R3 Adds Hysteresis to Low-Battery Detector

APPLICATIONS INFORMATION

Inductor Section

Inductors suitable for use with the LT1303 usually fall in the 5 μ H to 50 μ H range. The inductor must: (1) handle current of 1.25A without saturating, (2) have enough inductance to provide a di/dt lower than 400mA/ μ s, and (3) have low enough DC resistance to avoid excessive heating or efficiency losses. Higher value inductors will deliver more power but tend to be physically larger. Most ferrite core drum or rod inductors such as those specified in Table 1 are suitable for use. It is acceptable to bias openflux inductors (e.g. Sumida CD54) into saturation by 10 to 20% without adverse effects.

| VENDOR | SERIES | APPROPRIATE VALUES | PHONE NUMBERS |
|-------------|--|----------------------|------------------|
| Coilcraft | D03316 D01608 | 10µН to 47µН 10µН | (708) 639-6400 |
| Coiltronics | OCTAPAK CTX20-1 CTX20-2 CTX33-4 | 20µН 20µН 33µН | (407) 241-7876 |
| Sumida | CD54 | 10µН to 33µН | (708) 956-0666 |
| Gowanda | GA10 | 10µН to 33µН | (716) 532-2234 |

Table 1. Recommended Inductors

hysteresis built in, but hysteresis can be added by connecting a high-value resistor from LBI to LBO as shown in Figure 5. The internal reference can be accessed via the comparator as shown in Figure 6.

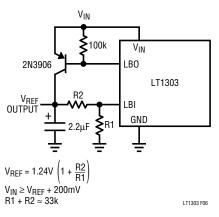
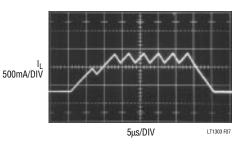
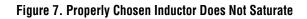


Figure 6. Accessing Internal Reference

Figure 7 shows inductor current of a suitable inductor, di/dt is controlled at all times. The rapid rise in current shown in Figure 8 results from this inductor saturating at approximately 1A. Saturation occurs when the inductor cannot hold any more magnetic energy in the core. Current then increases rapidly, limited only by the resistance of the winding. Figure 9's inductor has high DC resistance which results in the exponential time constant shape of the inductor current.







APPLICATIONS INFORMATION

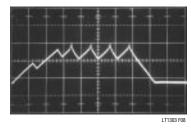


Figure 8. This Inductor Saturates at $I_L{\approx}1A.$ A Poor Choice

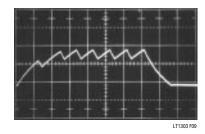


Figure 9. Slight Exponential Shape to Inductor Current Waveform Indicates Excessive DC Resistance

Diode Selection

The LT1303's high switching speed demands a high speed rectifier. Schottky diodes are preferred for their low forward drop and fast recovery. Suitable choices include the 1N5817, MBRS120LT3, and MBR0520LT1. Do not use signal diodes such as 1N4148. They cannot carry 1A current. Also avoid "general-purpose" diodes such as 1N4001. These are far too slow and are unsuitable for any switching regulator application. For high temperature applications a silicon diode such as the MUR105 will have less leakage.

Capacitor Selection

Input and output capacitors should have low ESR for best efficiency. Recommended capacitors include AVX TPS series, Sprague 595D series, and Sanyo OS-CON. The output capacitor's ESR determines the high frequency ripple amplitude. A 100 μ F capacitor is the minimum recommended for a 5V output. Higher output voltages can use lower capacitance values. For example, a 12V output can use a 33 μ F or 47 μ F capacitor. The V_{IN} pin of the LT1303 should be decoupled with a 47 μ F or 100 μ F capacitor at the pin. When driving a transformer, an additional decoupling network of 10 Ω and 0.1 μ F ceramic is recommended as shown in Figure 10.

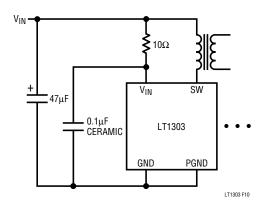


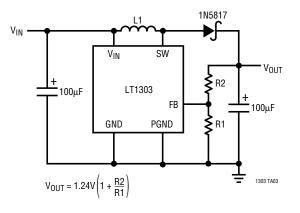
Figure 10. 10 Ω -1 μF Network to LT1303 V $_{IN}$ Pin Provides Additional Decoupling. Recommended When Driving Transformers.

| Table 2. | Recommended | Capacitors |
|----------|-------------|------------|
|----------|-------------|------------|

| VENDOR | SERIES | ТҮРЕ | PHONE NUMBERS |
|-----------|--------|---------------|------------------|
| AVX | TPS | Surface Mount | (803) 448-9411 |
| Sanyo | OS-CON | Through-Hole | (619) 661-6835 |
| Panasonic | HFQ | Through-Hole | (201) 348-5200 |
| Sprague | 595D | Surface Mount | (603) 224-1961 |

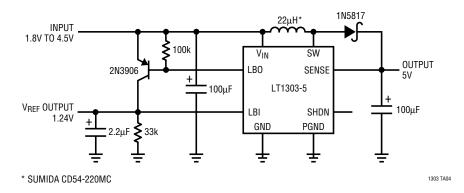


TYPICAL APPLICATIONS



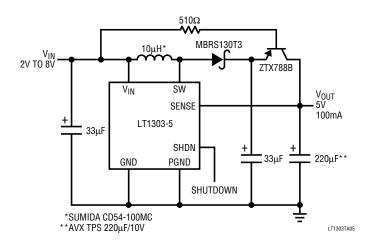
Setting Output Voltage on LT1303

5V Step-Up Converter with Reference Output



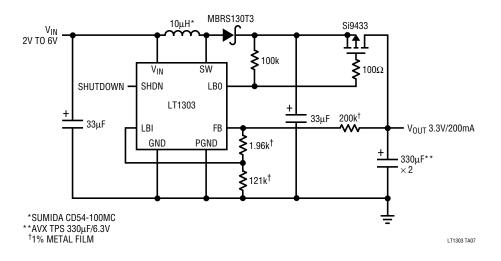


TYPICAL APPLICATIONS



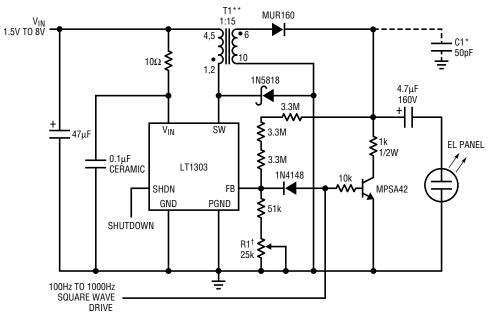
4-, 5-Cell to 5V Converter with Output Disconnect

3-Cell to 3.3V Boost/Linear Converter with Output Disconnect





TYPICAL APPLICATIONS



EL Panel Driver

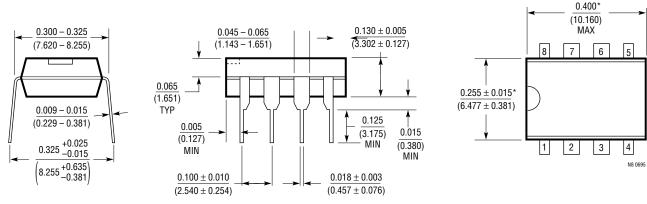
*ADD C1 FOR OPEN-PANEL PROTECTION **DALE LPE5047-A132 1:15 TURNS RATIO (605) 666-9301 [†]R1 ADJUSTS V_{OUT} 83V_{RMS} TO 115V_{RMS}

LT1303 TA06



Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of circuits as described herein will not infringe on existing patent rights.

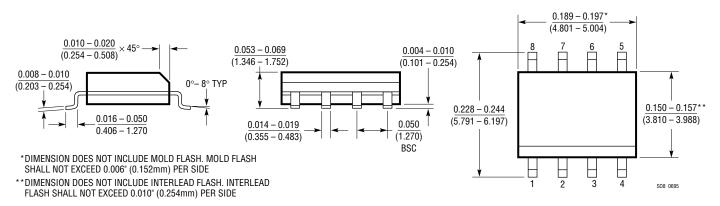
PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.



N8 Package 8-Lead Plastic DIP

*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

> S8 Package 8-Lead Plastic SOIC



RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
|-----------------------|--|---|
| LT1129 | Micropower Low Dropout Regulator | 700mA Output Current in SO-8 Package |
| LT1182/83/84 | LCD and CCFL Backlight Controller | High Efficiency and Excellent Backlight Control Range |
| LT1301 | 5V to 12V/200mA Step-Up DC/DC Converter | 120µA Quiescent Current |
| LT1302 | 2-Cell to 5V/600mA Step-Up DC/DC Converter | 200µA Quiescent Current |
| LT1305 | Micropower 2A Switch DC/DC Converter with Low-Battery Detect | 2V to 5V at 400mA |
| LT1372 | 500kHz Step-Up PWM, 1.5A Switch | Low Noise, Fixed Frequency Operation |
| LTC [®] 1472 | PCMCIA Host Switch with Protection | Includes Current Limit and Thermal Shutdown |